Cite this: *Phys. Chem. Chem. Phys.*,
2021, 23, 23389

Van der Waals heterostructure of graphene and germanane: tuning the ohmic contact by electrostatic gating and mechanical strain

A. Bafekry,^a S. Karbasizadeh,^b M. Faraji,^c A. Bagheri Khatibani,^d
I. Abdolhosseini Sarsari,^b D. Gogova^e and M. Ghergherehchi^{*f}

DOI: 10.1039/d1cp90197d

rsc.li/pccp

Correction for 'Van der Waals heterostructure of graphene and germanane: tuning the ohmic contact by electrostatic gating and mechanical strain' by A. Bafekry *et al.*, *Phys. Chem. Chem. Phys.*, 2021, DOI: 10.1039/D1CP03632G.

The authors would like to correct addresses 'e' and 'f' in the affiliation list as these were incorrectly swapped in the published article. The corrected affiliations for this paper are as shown below.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

^a Department of Radiation Application, Shahid Beheshti University, 19839 69411 Tehran, Iran. E-mail: bafekry.asad@gmail.com

^b Department of Physics, Isfahan University of Technology, Isfahan, 84156-83111, Iran

^c TOBB University of Economics and Technology, Sogutozu Caddesi No 43 Sogutozu, 06560, Ankara, Turkey

^d Nano Research Lab, Lahijan Branch, Islamic Azad University, 1616, Lahijan, Iran

^e Department of Physics, Chemistry and Biology, Linköping University, 58183, Linköping, Sweden

^f Department of Electrical and Computer Engineering, Sungkyunkwan University, 16419, Suwon, Korea. E-mail: mitragh@skku.edu